

Phase equilibria in the Gd–Al–Ge system at 873 K

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The interaction of the components in the ternary system Gd–Al–Ge was investigated by X-ray powder diffraction, scanning electron microscopy, and energy-dispersive X-ray spectroscopy. The isothermal section of the phase diagram at 873 K was constructed in the full concentration range, based on phase analysis of 48 alloys (Fig. 1). Samples were prepared by melting pure metals in an arc furnace under an argon atmosphere and annealed in evacuated quartz tubes for 720 h at 873 K.

According to literature data [1,2] eight gadolinium aluminides and twelve gadolinium germanides form in the binary systems Gd–Al and Gd–Ge, respectively, and ten ternary gadolinium alumogermanides are known in the system Gd–Al–Ge. The existence and crystal structures of ten binary gadolinium aluminides (GdAl₃, GdAl₂, Gd₃Al₂, GdAl, and Gd₂Al) and germanides (Gd₃Ge₅, GdGe_{1.56}, GdGe, Gd₅Ge₄, and Gd₅Ge₃) at the temperature of investigation was confirmed by X-ray diffraction. The solubility limits of the third component in several of the binary compounds were determined: GdAl₃ and GdAl₂ dissolve ~5 at.% Ge each, whereas Gd₃Ge₅, GdGe_{1.56}, and GdGe dissolve ~12, ~6, and ~5 at.% Al, respectively. The formation of seven ternary compounds was observed and their unit-cell parameters were refined: GdAl₂Ge₂ (structure type Ce₂SO₂, Pearson symbol *hP5*, space group *P-3m1*, *a* = 4.2425(7), *c* = 6.699(1) Å), Gd₂Al_{1.6}Ge_{5.4} (La₂AlGe₆, *mS36*, *C2/m*, *a* = 8.047(3), *b* = 8.364(4), *c* = 10.572(2) Å, β = 100.78°), Gd₂Al₃Ge₄ (Ba₂Cd₃Bi₄, *oS36*, *Cmce*, *a* = 5.9578(7), *b* = 14.864(2), *c* = 7.762(1) Å), Gd₂Al_{3.05}Ge₃ (Tb₂Al_{3.15}Ge₃, *hR234*, *R-3c*, *a* = 7.2746(6), *c* = 88.583(9) Å), GdAl_{0.15}Ge_{2.01} (ErGe_{2.16}, *oS16*, *Cmcm*, *a* = 4.174(1), *b* = 16.449(5), *c* = 3.982(1) Å), Gd₂AlGe₃ (Y₂AlGe₃, *oP24*, *Pnma*, *a* = 6.8031(2), *b* = 4.2283(1), *c* = 17.8166(5) Å), GdAlGe ht (α -ThSi₂, *tI12*, *I4₁/amd*, *a* = 4.1431(5), *c* = 14.338(2) Å). Three other compounds, GdAl_{0.26}Ge₃, Gd₂AlGe₂, and Gd₁₁Al₂Ge₈, mentioned in the literature, were not observed at 873 K.

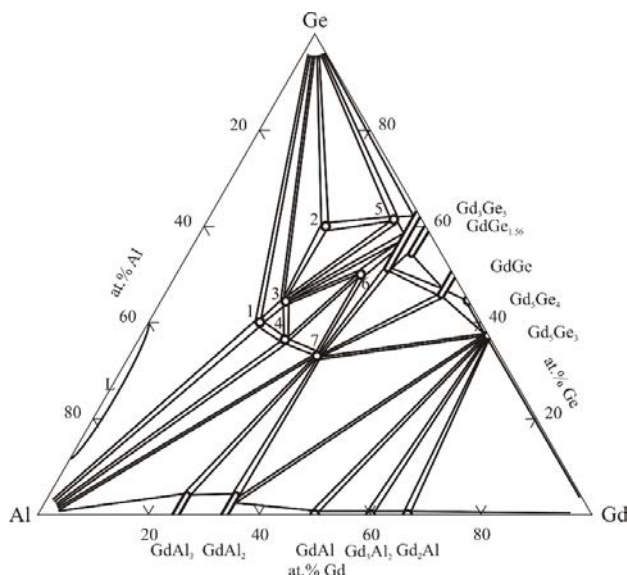


Figure 1. Isothermal section of the phase diagram of the system Gd–Al–Ge at 873 K; compounds: GdAl₂Ge₂ (1), Gd₂Al_{1.6}Ge_{5.4} (2), Gd₂Al₃Ge₄ (3), Gd₂Al_{3.05}Ge₃ (4), GdAl_{0.15}Ge_{2.01} (5), Gd₂AlGe₃ (6), GdAlGe ht (7).

[1] Villars, P., Cenzual, K., Daams, J. L. C., Hulliger, F., Okamoto, H., Osaki, K., Prince, A. & Iwata, S. (2002). *Pauling File Binaries Edition, Release 2002/1*. Bonn; Crystal Impact (Distributor).

[2] *Pearson's Crystal Data, Crystal Structure Database for Inorganic Compounds, Release 2024/25*, edited by P. Villars & K. Cenzual, 2024. Materials Park (OH): ASM International.

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